Littelfuse Power

# LSIC2SD065D10A 650 V, 10 A SiC Schottky Barrier Diode 🛛 📾 AUTOMOTIVE GRADE HF Rolls 🚱



#### Circuit Diagram TO-263-2L



## Description

This series of silicon carbide (SiC) Schottky diodes has negligible reverse recovery current, high surge capability, and a maximum operating junction temperature of 175 °C. These diodes series are ideal for applications where improvements in efficiency, reliability, and thermal management are desired.

• Excellent surge capability

temperature-independent

switching behavior

• Dramatically reduced

compared to Si bipolar

• Industrial motor drives

• EV charging stations

switching losses

diodes

• Solar inverters

Extremely fast,

## Features

- AEC-Q101 qualified
- Positive temperature coefficient for safe operation and ease of paralleling
- 175 °C maximum operating junction temperature

## Applications

- Boost diodes in PFC or DC/DC stages
- Switch-mode power supplies
- Uninterruptible power supplies

#### Environmental

- Littelfuse "RoHS" logo = RoHS RoHS conform
- Littelfuse "HF" logo = **HF** Halogen Free
- Littelfuse "Pb-free" logo = 100 Pb-free lead plating

Characteristics	Symbol	Conditions	Value	Unit	
Repetitive Peak Reverse Voltage	V <sub>RRM</sub>	-	650	V	
DC Blocking Voltage	V <sub>R</sub>	T <sub>J</sub> = 25 °C	650	V	
		T <sub>c</sub> = 25 °C	27		
Continuous Forward Current	l <sub>F</sub>	T <sub>c</sub> = 135 °C	12.5	A	
		$T_c = 147 \text{ °C}$	10		
Non-Repetitive Forward Surge Current	   <sub>FSM</sub>	$T_c = 25 \text{ °C}, T_p = 10 \text{ ms}, \text{ Half sine pulse}$	48	A	
Power Dissipation	T. = 25 °C		100	W	
	P <sub>Tot</sub>	$T_c = 110 \text{ °C}$	43		
Operating Junction Temperature	TJ	-	-55 to 175	°C	
Storage Temperature	T <sub>stg</sub>	-	-55 to 150	°C	
Soldering Temperature	T <sub>SOLD</sub>	-	260	°C	

## **Maximum Ratings**

Electrical Characteristics (T <sub>J</sub> = 25 °C unless otherwise specified)						
			Value			
Characteristics	Symbol	Conditions	Min.	Тур.	Max.	Unit
		I <sub>F</sub> = 10 A, Τ <sub>J</sub> = 25 °C	-	1.5	1.8	V
Forward Voltage	V <sub>F</sub>	I <sub>F</sub> = 10 A, Τ <sub>J</sub> = 175 °C	-	1.85	-	V
Reverse Current I <sub>R</sub>	V <sub>R</sub> = 650 V , T <sub>J</sub> = 25 °C	-	<1	50		
	R	V <sub>R</sub> = 650 V , T <sub>J</sub> = 175 °C	-	25	-	μA
		V <sub>B</sub> = 1 V, f = 1 MHz	-	470	-	
Total Capacitance	С	V <sub>R</sub> = 200 V, f = 1 MHz	-	60	-	pF
		V <sub>R</sub> = 400 V, f = 1 MHz	-	43	-	
Total Capacitive Charge	Q <sub>c</sub>	$V_{R} = 400 \text{ V},  Q_{c} = \int_{0}^{V_{R}} C(V) dV$	-	30	-	nC

## Thermal Characteristics

Characteristics	Symbol	Value	Unit	
Thermal Resistance	R <sub>ejc</sub>	1.5	°C/W	



## Figure 2: Typical Reverse Characteristics



#### Figure 3: Power Derating



## Figure 5: Capacitance vs. Reverse Voltage



## Figure 7: Stored Energy vs. Reverse Voltage



#### Figure 4: Current Derating



#### Figure 6: Capacitive Charge vs. Reverse Voltage



## **Figure 8: Transient Thermal Impedance**



## Dimensions-Package TO-263-2L



Dort N	lumborin	g and Ma	rking S	vetom
Fallin	unnbenn	y anu wa	ткшу э	ystem



= SiC Diode
= Gen2
= Schottky Diode

- = Voltage Rating (650 V)
- = TO-263-2L (D2PAK)
- = Current Rating (10 A)
- = Year
- = Week
- X = Special Code ZZZZZ-ZZ = Lot Number

Symbol	Millimeters			
Symbol	Min	Max		
А	4.30	4.50	4.70	
A1	0.00	-	0.25	
b	0.70	0.80	0.90	
b1	1.17	1.27	1.37	
С	0.46	0.50	0.60	
c1	1.25	1.30	1.40	
D	9.00	9.20	9.40	
D1	6.50	6.70	6.90	
Е	9.80	10.00	10.20	
E1	7.80	8.00	8.20	
E2	9.70	9.90	10.10	
е		5.08 BSC		
Н	15.00	15.30	15.60	
L	2.00	2.30	2.60	
L1	1.00	1.20	1.40	
L2	0.254 BSC			

Dacking	Ontion
Packing	Option

Part Number	Marking	Packing Mode	M.O.Q
LSIC2SD065D10A	SIC2SD065D10	Tape and Reel	800



## GEN2 SiC Schottky Diode LSIC2SD065D10A, 650 V, 10 A, TO-263-2L (D2PAK)

#### **TO-263 Carrier Reel Specifications**



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